

Dual - MOSMIC[®] – two AGC Amplifiers for TV-Tuner Prestage with 5 V Supply Voltage

MOSMIC - MOS Monolithic Integrated Circuit

Electrostatic sensitive device.
Observe precautions for handling.

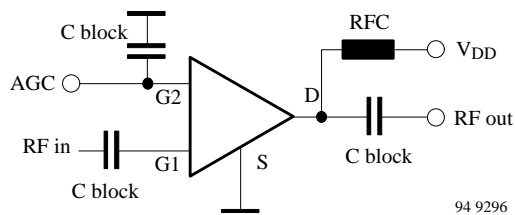


Applications

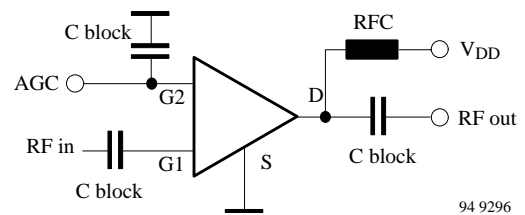
Low noise gain controlled input stages in UHF-and VHF- tuner with 5 V supply voltage.

Typical Application

Amplifier 1

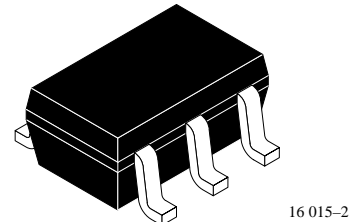
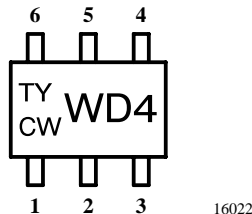


Amplifier 2



Features

- Two AGC amplifiers in a single package
- Integrated gate protection diodes
- Low noise figure
- High gain, high forward transadmittance (40 mS typ.)
- Biasing network on chip
- Improved cross modulation at gain reduction
- High AGC-range
- SMD package



TSDF54040 Marking: WD4

Plastic case (SOT 363)

1 = Gate 1 (amplifier 1), 2 = Gate 2, 3 = Drain (amplifier 1),
4 = Drain (amplifier 2), 5 = Source, 6 = Gate1 (amplifier 2)

T = Telefunken

Y = Year, is variable for digit from 0 to 9 (e.g. 9 = 1999, 0 = 2000)

CW = Calendar Week, is variable for number from 01 to 52

Number of Calendar Week is always indicating place of pin 1

All of following data and characteristics are valid for operating either amplifier 1 (pin 1, 3, 2, 5) or amplifier 2 (pin 6, 4, 2, 5)

Absolute Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Drain - source voltage		V_{DS}	8	V
Drain current		I_D	30	mA
Gate 1/Gate 2 - source peak current		$\pm I_{G1/G2SM}$	10	mA
Gate 1/Gate 2 - source voltage		$\pm V_{G1/G2SM}$	6	V
Total power dissipation Channel temperature	$T_{amb} \leq 60^{\circ}\text{C}$	P_{tot}	200	mW

Electrical AC Characteristics

$V_{DS} = 5\text{ V}$, $V_{G2S} = 4\text{ V}$, $f = 1\text{ MHz}$, $T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Forward transadmittance		$ y_{21s} $	35	40	50	mS
Gate 1 input capacitance		C_{issg1}		2.7	3.5	pF
Feedback capacitance		C_{rss}		30		fF
Output capacitance		C_{oss}		1.5		pF
Power gain	$G_S = 2\text{ mS}$, $G_L = 0.5\text{ mS}$, $f = 200\text{ MHz}$	G_{ps}		28		dB
	$G_S = 3,3\text{ mS}$, $G_L = 1\text{ mS}$, $f = 800\text{ MHz}$	G_{ps}	20	23		dB
AGC range	$V_{DS} = 5\text{ V}$, $V_{G2S} = 1\text{ to }4\text{ V}$, $f = 800\text{ MHz}$	ΔG_{ps}		45		dB
Noise figure	$G_S = 2\text{ mS}$, $G_L = 0.5\text{ mS}$, $f = 200\text{ MHz}$	F		1		dB
	$G_S = 3,3\text{ mS}$, $G_L = 1\text{ mS}$, $f = 800\text{ MHz}$	F		1.3		dB
Cross modulation	Input level for $k = 1\%$ @ 0 dB AGC $f_w = 50\text{ MHz}$, $f_{unw} = 60\text{ MHz}$	X_{mod}	85			dB μ V
	Input level for $k = 1\%$ @ 40 dB AGC $f_w = 50\text{ MHz}$, $f_{unw} = 60\text{ MHz}$	X_{mod}	100			dB μ V

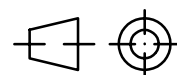
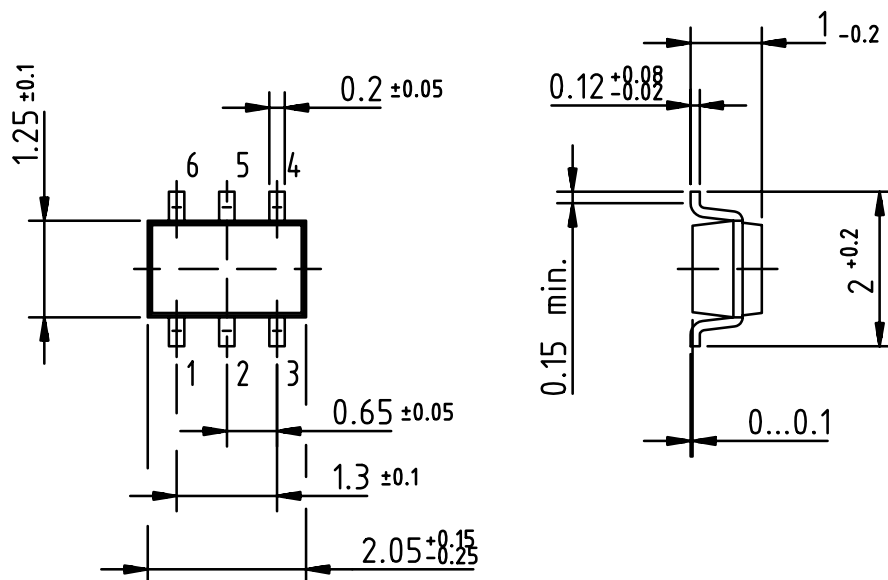
Caution for Gate 1 switch-off mode:

No external DC-voltage on Gate 1 in active mode!

Switch-off at Gate 1 with $V_{G1S} < 0.7\text{ V}$ is feasible.

Using open collector switching transistor (inside of PLL), insert 10 k Ω collector resistor.

Dimensions of TSDF54040 in mm



technical drawings
according to DIN
specifications

14280



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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